

MIC2981/2982

High-Voltage High-Current Source Driver Array

Preliminary Information

General

The MIC2981/82 is an 8-channel, high-voltage, high-current source driver array ideal for switching high-power loads from logic-level TTL, CMOS, or PMOS control signals.

These drivers can manage multiple loads of up to 50V and 500mA, limited only by package power dissipation.

Micrel's MIC2981/82 features inputs compatible with 5V TTL and 5V to 15V CMOS or PMOS logic outputs. Micrel's dual-marked device replaces either UDN2981 or UDN2982 devices.

The MIC2981/82 is available in the 18-pin plastic DIP and 18-lead wide SOP package. Both devices operate in the industrial temperature range.

Features

- Output voltage to 50V
- Output current to 500mA
- Transient-protected outputs
- Integral clamp diodes
- TTL, CMOS, or PMOS compatible inputs

Applications

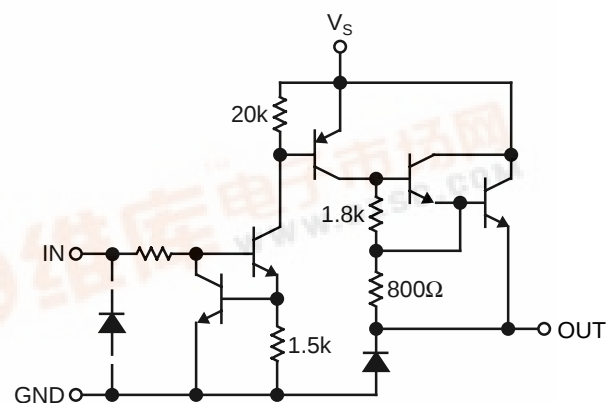
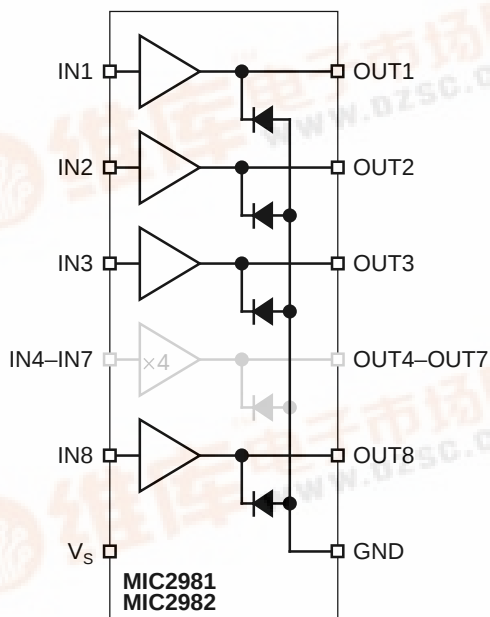
- Relay and solenoid switching
- Stepping motor
- LED and incandescent displays

Ordering Information

Part Number	Temperature Range	Package
MIC2981BN/ MIC2982BN*	-40°C to +85°C	18-pin DIP
MIC2981BWM/ MIC2982BWM*	-40°C to +85°C	18-pin wide SOP

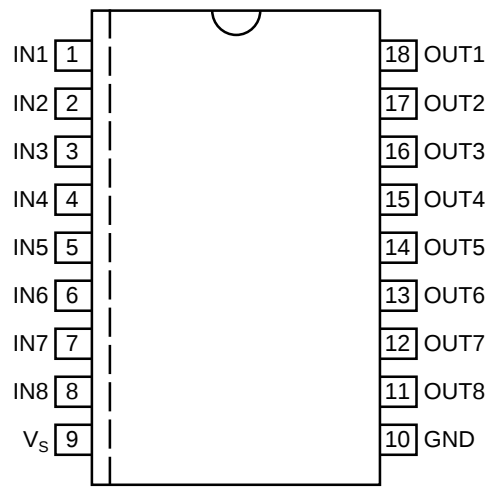
* Orders for MIC2981BN or MIC2982BN will be filled with dual-marked MIC2981/82BN. Orders for MIC2981BWM or MIC2982BWM will be filled with dual-marked MIC2981/82BWM.

Functional Diagrams



Typical MIC2981/2982 Source Driver

Pin Configuration



18-Pin DIP (N)
18-Pin Wide SOP (WM)

Pin Description

Pin No.	Pin No.	Pin Name	Pin Function
1–8	IN1–IN8	Input 1 through Input 8:	Base drive to driver input transistor.
9	V _S	Supply Input	
10	GND	Ground	
11–18	OUT8–OUT1	Output 8 through Output 1:	Emitter of Darlington driver output.

Absolute Maximum Ratings

Supply Voltage (V_S)	50V
Output Voltage (V_{CE})	50V
Continuous Output Current (I_C)	500mA
Input Voltage (V_{IN})	
MIC2981/82	30V
Ground Current (I_{GND})	3A
Junction Temperature (T_J)	+150°C
Storage Temperature (T_S)	–65°C to +150°C

Operating Ratings

Supply Voltage (V_S)	5V to 50V
Ambient Temperature (T_A)	–40°C to +85°C
Package Thermal Resistance	
PDIP θ_{JA}	56°C/W
SOP θ_{JA}	84°C/W

Electrical Characteristics

$V_S = 50V$, $T_A = +25^\circ C$, unless noted.

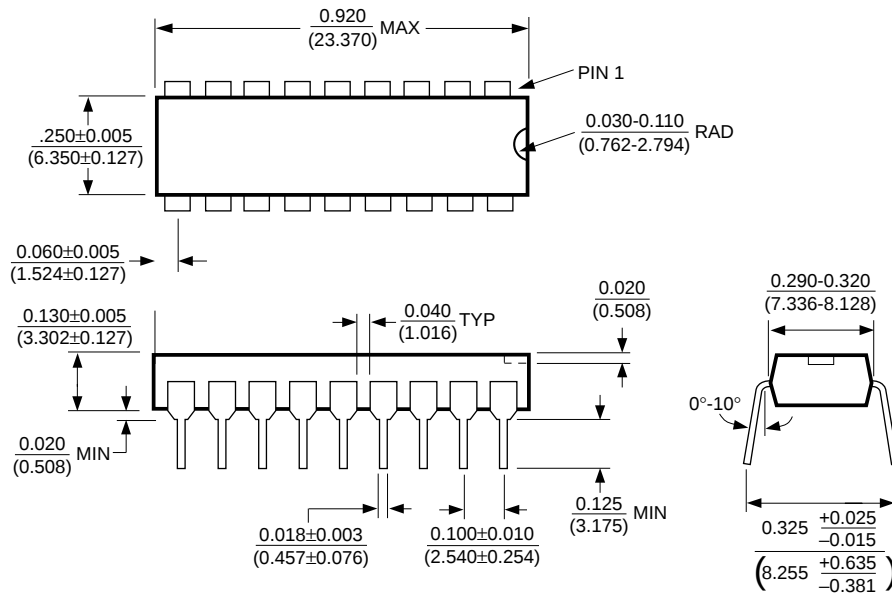
Symbol	Parameter	Condition	Min	Typ	Max	Units
I_{CEX}	Output Leakage Current	$V_{IN} = 0.4V$, $T_A = +70^\circ C$, Note 1			200	μA
$V_{CE(sus)}$	Output Sustaining Voltage	$I_{OUT} = 45mA$	35			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$V_{IN} = 2.4V$, $I_{OUT} = 100mA$ $V_{IN} = 2.4V$, $I_{OUT} = 225mA$ $V_{IN} = 2.4V$, $I_{OUT} = 350mA$		1.7 1.8 1.9	2.0 2.1 2.2	V V V
$I_{IN(on)}$	Input Current	MIC2981 $V_{IN} = 2.4V$ $V_{IN} = 3.85$		140 310	200 450	μA μA
		MIC2982 $V_{IN} = 2.4V$ $V_{IN} = 12V$		140 1.25	200 1.93	μA mA
I_{OUT}	Output Source Current	$V_{IN} = 2.4V$, $V_{CE} = 2.2V$	350			mA
I_S	Supply Current	$V_{IN} = 2.4$, OUT1–8 = open, Note 1			10	mA
t_{ON}	Turn-On Delay	$0.5E_{IN}$ to $0.5E_{OUT}$, $R_L = 100\Omega$, $V_S = 35V$,		1.0	2.0	μs
t_{OFF}	Turn-Off Delay	$0.5E_{IN}$ to $0.5E_{OUT}$, $R_L = 100\Omega$, $V_S = 35V$, Note 2		5.0	10	μs
I_R	Clamp Diode Leakage Current	$V_R = 50V$, $V_{IN} = 0.4V$, Note 1			50	μA
V_F	Clamp Diode Forward Voltage	$I_F = 350mA$		1.5	2.0	V

General Note: Devices are ESD protected; however, handling precautions are recommended.

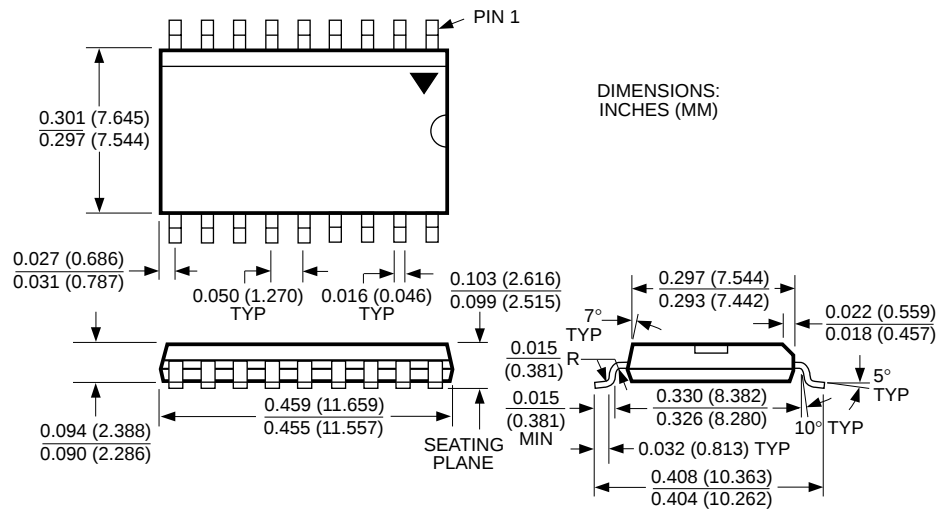
Note 1: Applied to all 8 inputs simultaneously.

Note 2: Load conditions affect turnoff delay.

Package Information



18-Pin Plastic DIP (N)



18-Pin Wide SOP (WM)